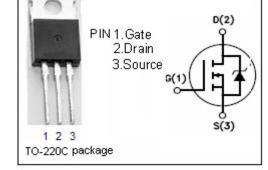


# isc N-Channel MOSFET Transistor

2SK1323

#### **DESCRIPTION**

- Drain Current –I<sub>D</sub>= 2A@ T<sub>C</sub>=25 °C
- Drain Source Voltage-
  - : V<sub>DSS</sub>= 800V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



#### **APPLICATIONS**

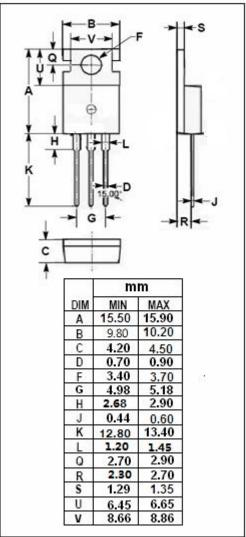
• Designed for high voltage, high speed power switching.



SYMBOL	ARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage (V <sub>GS</sub> =0)	800	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-continuous@ TC=25℃ 2		Α
P <sub>tot</sub>	Total Dissipation@TC=25℃ 75		W
T <sub>j</sub>	Max. Operating Junction Temperature	perating Junction Temperature 150	
T <sub>stg</sub>	Storage Temperature Range -55-		$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	0.83	°C/W	
R <sub>th j-a</sub>	R <sub>th j-a</sub> Thermal Resistance,Junction to Ambient		°C/W	





## isc N-Channel Mosfet Transistor

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### • ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0; I <sub>D</sub> = 10mA	800			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =10 V <sub>GS</sub> ; I <sub>D</sub> =1mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-stage Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =1A			6.50	Ω
I <sub>GSS</sub>	Gate Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =800V; V <sub>GS</sub> = 0			500	uA



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